

Wespack Phase Control Thyristor

Types N2191ML160 to N2191ML180

Development Type No.: NX313ML160-180

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{DRM}	Repetitive peak off-state voltage, (note 1)	1600-1800	V
V_{DSM}	Non-repetitive peak off-state voltage, (note 1)	1600-1800	V
V_{RRM}	Repetitive peak reverse voltage, (note 1)	1600-1800	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	1500-1900	V

	OTHER RATINGS		MAXIMUM LIMITS	UNITS
I _{T(AV)M}	Maximum average on-state current, T _{sink} =55°C, (note 2)		2191	A
I _{T(AV)M}	Maximum average on-state current. T _{sink} =85°C, (note 2)		1476	A
I _{T(AV)M}	Maximum average on-state current. T _{sink} =85°C, (note 3)		743	A
I _{T(RMS)M}	Nominal RMS on-state current, T _{sink} =25°C, (note 2)		4366	A
I _{T(d.c.)}	D.C. on-state current, T _{sink} =25°C, (note 4)		3685	A
I _{TSM}	Peak non-repetitive surge t _p =10ms, V _{rm} =60%V _{RRM} , (note 5)		34.5	kA
I _{TSM2}	Peak non-repetitive surge t _p =10ms, V _{rm} ≤10V, (note 5)		38.0	kA
I ² t	I ² t capacity for fusing t _p =10ms, V _{rm} =60%V _{RRM} , (note 5)		5.95×10 ⁶	A ² s
I ² t	I ² t capacity for fusing t _p =10ms, V _{rm} ≤10V, (note 5)		7.22×10 ⁶	A ² s
(di/dt) _{cr}	Critical rate of rise of on-state current (note 6)	(continuous, 50Hz)	100	A/μs
		(repetitive, 50Hz, 60s)	200	
		(non-repetitive)	400	
V _{RGM}	Peak reverse gate voltage		5	V
P _{G(AV)}	Mean forward gate power		4	W
P _{GM}	Peak forward gate power		30	W
T _{j op}	Operating temperature range		-40 to +125	°C
T _{stg}	Storage temperature range		-40 to +150	°C

Notes:-

- 1) De-rating factor of 0.13% per $^{\circ}C$ is applicable for T_j below $25^{\circ}C$.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Cathode side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, $125^{\circ}C$ T_j initial.
- 6) $V_D=67\% V_{DRM}$, $I_{TM}=2000A$, $I_{FG}=2A$, $t_r\leq 0.5\mu s$, $T_{case}=125^{\circ}C$.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V _{TM}	Maximum peak on-state voltage	-	-	1.40	I _{TM} =3000A	V
V _{TM}	Maximum peak on-state voltage	-	-	2.15	I _{TM} =7800A	V
V _{T0}	Threshold voltage	-	-	0.940		V
r _T	Slope resistance	-	-	0.154		mΩ
(dv/dt) _{cr}	Critical rate of rise of off-state voltage	1000	-	-	V _D =80% V _{DRM} , linear ramp, gate o/c	V/μs
I _{DRM}	Peak off-state current	-	-	100	Rated V _{DRM}	mA
I _{RRM}	Peak reverse current	-	-	100	Rated V _{RRM}	mA
V _{GT}	Gate trigger voltage	-	-	3.0	T _j =25°C V _D =10V, I _T =3A	V
I _{GT}	Gate trigger current	-	-	300		mA
V _{GD}	Gate non-trigger voltage	-	-	0.25		V
I _H	Holding current	-	-	1000	T _j =25°C	mA
t _{gd}	Gate-controlled turn-on delay time	-	0.8	2.0	V _D =67% V _{DRM} , I _T =2000A, di/dt=10A/μs, I _{FG} =2A, t _r =0.5μs, T _j =25°C	μs
t _{gt}	Turn-on time	-	1.4	3.0		μs
Q _{rr}	Recovered charge	-	3600	3900	I _{TM} =1000A, t _p =1000μs, di/dt=10A/μs, V _r =50V	μC
Q _{ra}	Recovered charge, 50% Chord	-	2150	-		μC
I _{rr}	Reverse recovery current	-	150	-		A
t _{rr}	Reverse recovery time	-	29	-		μs
t _q	Turn-off time	-	350	-	I _{TM} =1000A, t _p =1000μs, di/dt=10A/μs, V _r =50V, V _{dr} =80%V _{DRM} , dV _{dr} /dt=20V/μs	μs
		-	600	-	I _{TM} =1000A, t _p =1000μs, di/dt=10A/μs, V _r =50V, V _{dr} =80%V _{DRM} , dV _{dr} /dt=200V/μs	
R _{thJK}	Thermal resistance, junction to heatsink	-	-	0.018	Double side cooled	K/W
		-	-	0.033	Anode side cooled	K/W
		-	-	0.044	Cathode side cooled	K/W
F	Mounting force	25	-	31	Note 2.	kN
W _t	Weight	-	550	-		g

Notes:-

- 1) Unless otherwise indicated T_j=125°C.
- 2) For other clamp forces, please consult factory.

Curves

Figure 1 – On-state characteristics of Limit device

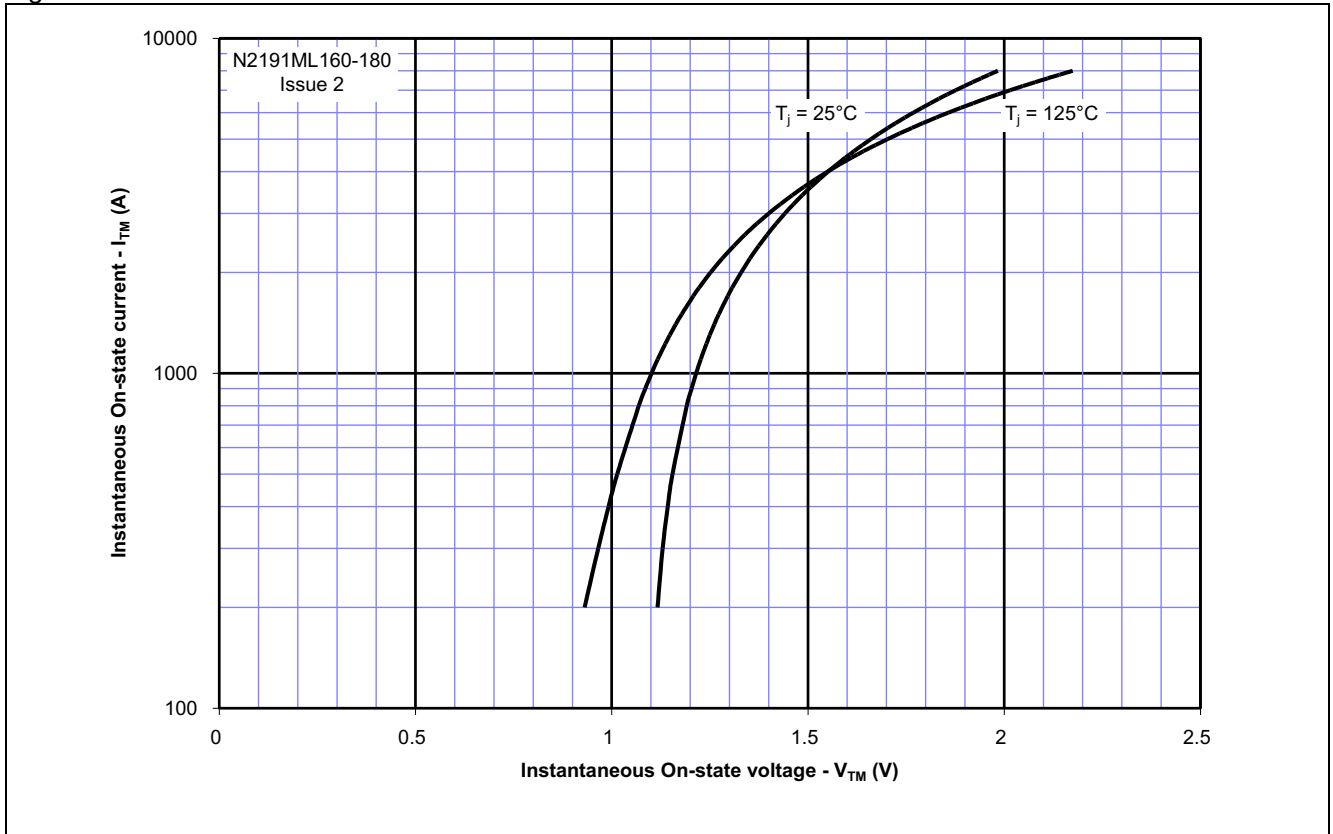


Figure 2 – Transient thermal impedance

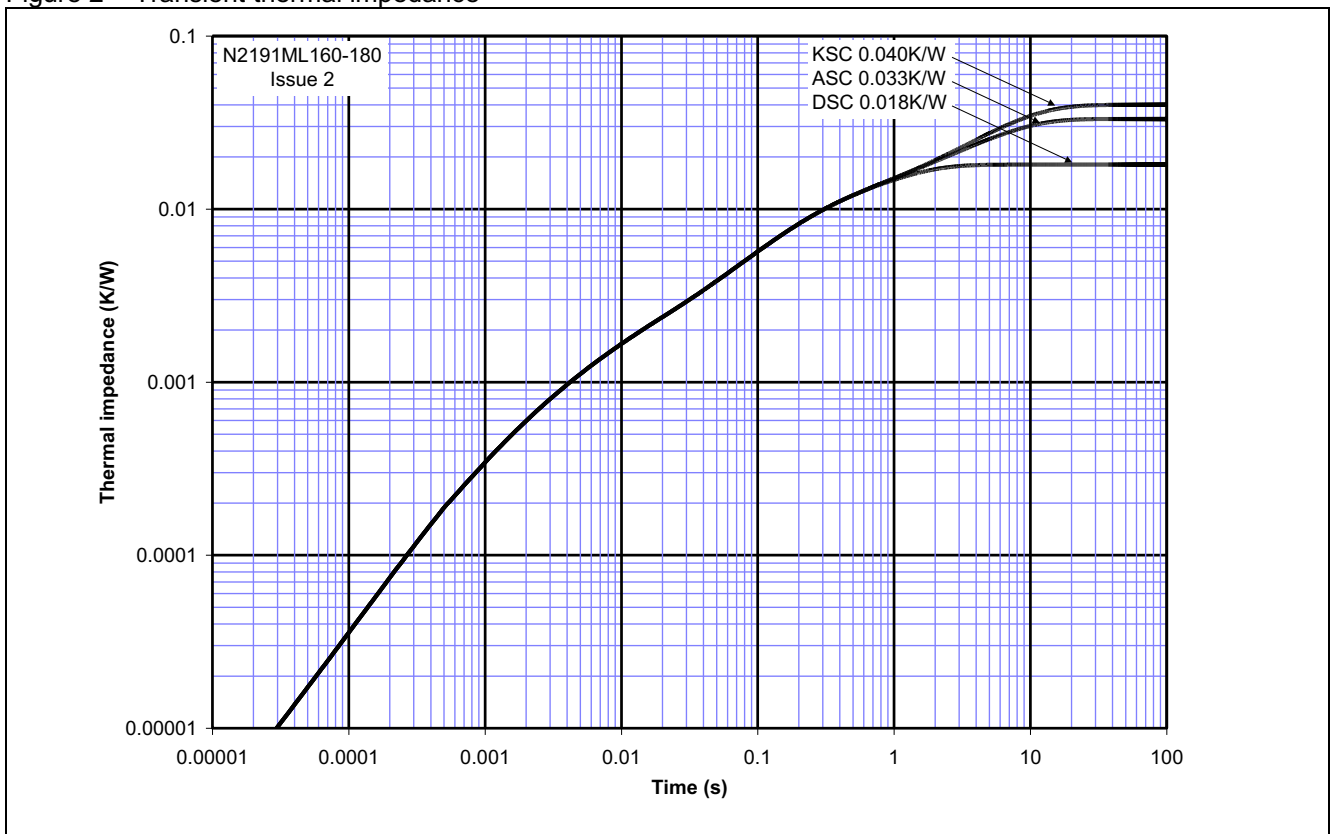
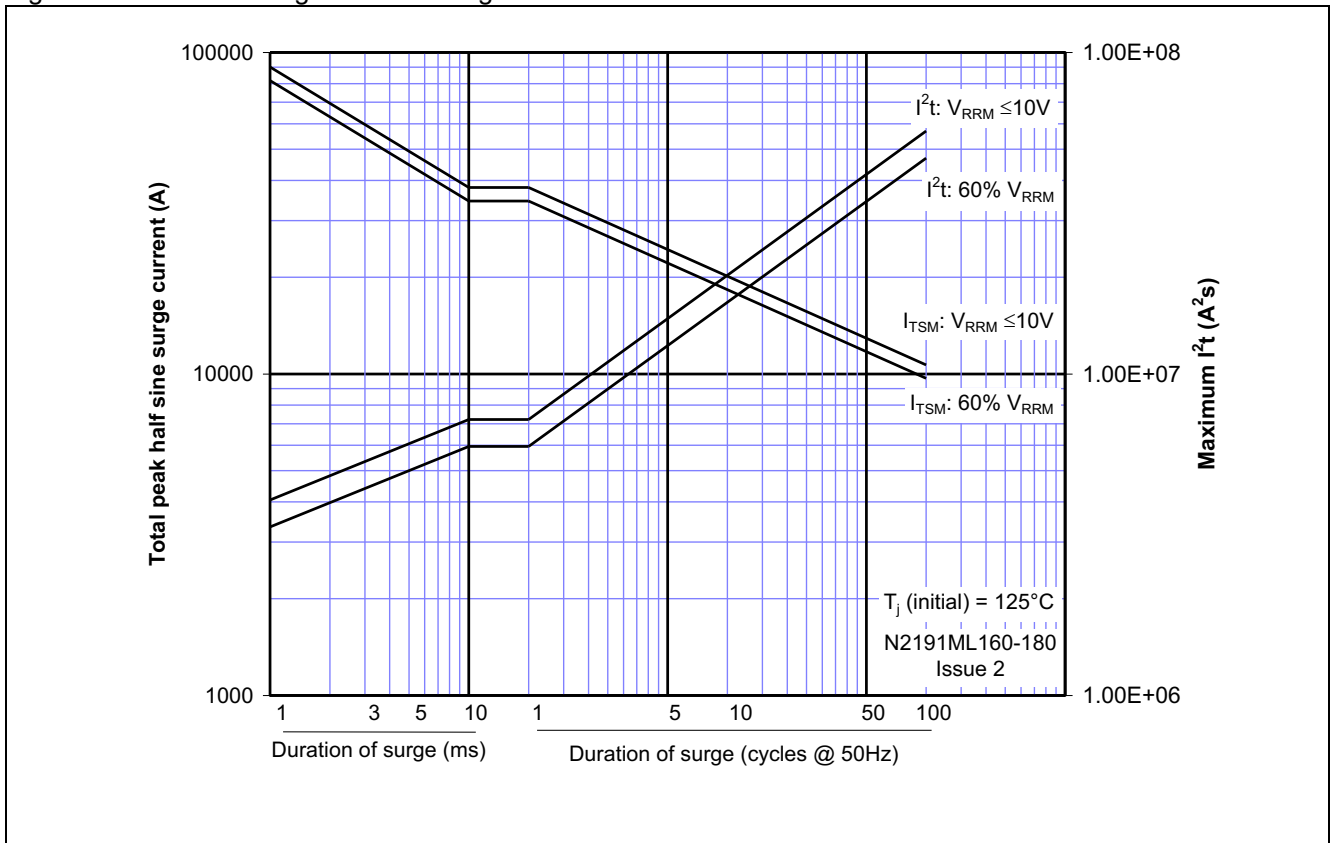
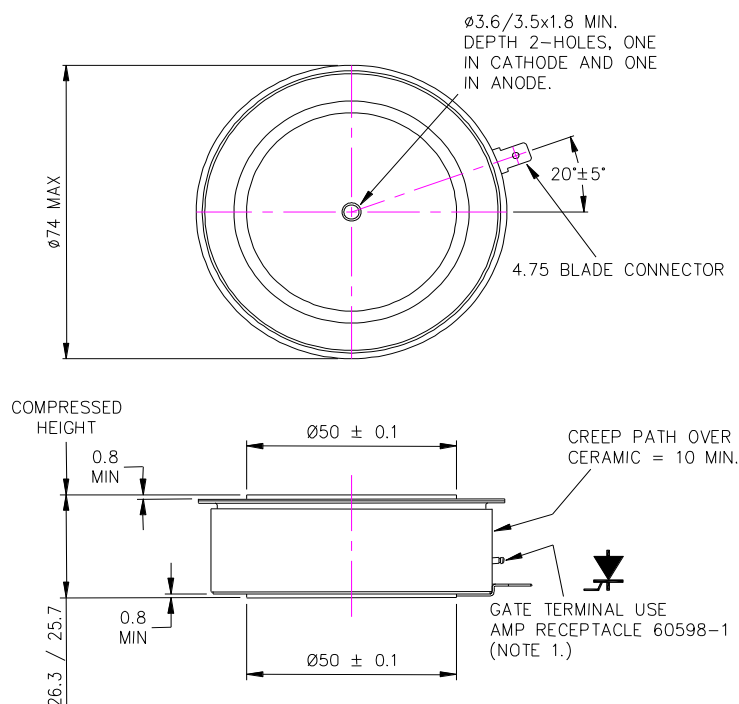


Figure 3 – Maximum surge and I^2t Ratings



Outline Drawing & Ordering Information



101A356

ORDERING INFORMATION

(Please quote 10 digit code as below)

N2191	ML	◆◆	0
Fixed Type Code	Fixed outline code	Voltage code $V_{DRM}/100$ 16-18	Fixed turn-off time code

Order code: N2191ML160 – 1600V V_{DRM} , V_{RRM} , 26mm clamp height capsule.

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